

SGM3003

Ultra Low ON-Resistance, Low Voltage, SPDT Analog Switch

GENERAL DESCRIPTION

The SGM3003 is a single, low ON-resistance, low voltage, bidirectional, single-pole/double-throw (SPDT) CMOS analog switches designed to operate from a single +1.8V to +5.5V supply. Targeted applications include battery powered equipment that benefit from low R_{ON} (0.5Ω) and fast switching speeds ($t_{ON} = 21\text{ ns}$, $t_{OFF} = 9\text{ ns}$).

The on resistance profile is very flat over the full analog signal range. This ensures excellent linearity and low distortion when switching audio signals.

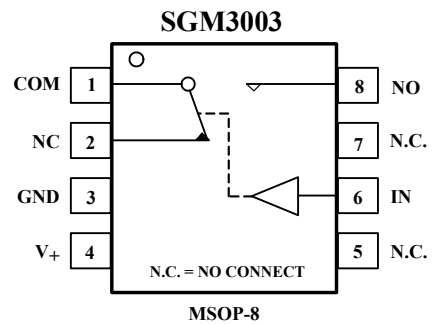
SGM3003 has one normally open switch and one normally closed switch. Each switch conducts equally well in both directions when on.

SGM3003 is available in a MSOP-8 package.

FEATURES

- Low Voltage Operation : 1.8 V to 5.5 V
- Low On-Resistance: 0.5Ω (TYP)
- Low On-Resistance Flatness
- -3 dB Bandwidth: 30 MHz
- Fast Switching Time($V_+ = 5V$)
 t_{ON} 21 ns
 t_{OFF} 9 ns
- Rail-to-Rail Operation
- Typical Power Consumption ($<0.01\text{ }\mu\text{W}$)
- TTL/CMOS Compatible
- Microsize Package

PIN CONFIGURATIONS (TOP VIEW)



APPLICATIONS

Battery powered, Handheld, and Portable Equipments
Cellular/mobile Phones
Laptops, Notebooks, Palmtops
Communication Systems
Sample-and-Hold Circuits
Audio Signal Routing
Audio and Video Switching
Portable Test and Measurement
Medical Equipment

FUNCTION TABLE

LOGIC	NC	NO
0	ON	OFF
1	OFF	ON



ORDERING INFORMATION

MODEL	PIN-PACKAGE	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKAGE OPTION
SGM3003	MSOP-8	- 40°C to +125°C	SGM3003XMS/TR	SGM3003XMS	Tape and Reel, 3000

ABSOLUTE MAXIMUM RATINGS

V₊ to GND.....- 0.3V to +6V
 Analog, Digital voltage range(1)..... - 0.3V to V₊ + 0.3V
 Continuous Current NO, NC, or COM.....± 300mA
 Peak Current NO, NC, or COM± 500mA
 Operating Temperature Range.....- 40°C to +125°C
 Junction Temperature.....+150°C
 Storage Temperature.....- 65°C to +150°C

Package Thermal Resistance @ T_A = 25°C

MSOP-8, θ_{JA}.....216°C/W

Lead Temperature (soldering, 10s).....260°C

ESD Susceptibility

HBM.....2000V

MM.....400V

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

(1) Signals on NC, NO, or COM or IN exceeding V₊ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

PIN DESCRIPTION

NAME	PIN	FUNCTION
V ₊	4	Power supply
GND	3	ground
IN	6	Digital control pin to connect the COM terminal to the NO or NC terminals
COM	1	Common terminal
NO	8	Normally-open terminal
NC	2	Normally-closed terminal
N.C.	5, 7	No internal connection

Note: NO, NC and COM terminal may be an input or output.

ELECTRICAL CHARACTERISTICS

(V₊ = +5 V ± 10%, GND = 0 V, T_A = - 40°C to +125°C, unless otherwise noted. Typical values are at T_A = + 25°C.)

PARAMETER	SYMBOL	CONDITIONS	SGM3003			
			+25℃	- 40℃ to +125℃	UNITS	MIN/ MAX
ANALOG SWITCH						
Analog Signal Range	V _{NO} , V _{NC} , V _{COM}			0	V	MIN
				V ₊	V	MAX
On-Resistance	R _{ON}	0 ≤ V _{NO} or V _{NC} ≤ V ₊ , I _{COM} = -10 mA, Test Circuit 1	0.5		Ω	TYP
			0.9	1.1	Ω	MAX
On-Resistance Flatness	R _{FLAT(ON)}	0 ≤ V _{NO} or V _{NC} ≤ V ₊ , I _{COM} = -10 mA, Test Circuit 1	0.13		Ω	TYP
			0.2	0.4	Ω	MAX
LEAKAGE CURRENTS						
Source OFF Leakage current	I _{NC(OFF)} , I _{NO(OFF)}	V _{NO} or V _{NC} = 4.5V/1V, V _{COM} = 1V/4.5V, V ₊ = +5.5V ,Test Circuit 2	±4		nA	TYP
			±10	±1000	nA	MAX
Channel ON Leakage current	I _{NC(ON)} , I _{NO(ON)} , I _{COM(ON)}	V _{NO} or V _{NC} = V _{COM} = 1V or 4.5V, V ₊ = +5.5V , Test Circuit 3	±4		nA	TYP
			±10	±1000	nA	MAX
DIGITAL INPUTS						
Input High Voltage	V _{INH}			2.4	V	MIN
Input Low Voltage	V _{INL}			0.8	V	MAX
Input Current	I _{INL} or I _{INH}	V _{IN} = V _{INH} or V _{INL}	±0.01		μA	TYP
			±0.1	±1	μA	MAX
DYNAMIC CHARACTERISTICS						
Turn-On Time	t _{ON}	V _{NO} or V _{NC} = 3V, R _L = 300Ω, C _L = 35pF, Test Circuit 4	21		ns	TYP
Turn-Off Time	t _{OFF}	V _{NO} or V _{NC} = 3V, R _L = 300Ω, C _L = 35pF, Test Circuit 4	9		ns	TYP
Charge Injection,	Q	C _L = 1.0nF, V _G = 0V, R _G = 0, Test Circuit 5	5		pC	TYP
Break-Before-Make Time Delay	t _D	V _{NO1} or V _{NC1} = V _{NO2} or V _{NC2} = 3V, R _L = 300Ω, C _L = 35pF, Test Circuit 6	10		ns	TYP
Off Isolation	O _{ISO}	R _L = 50Ω, C _L = 5pF, f = 100KHz	-55		dB	TYP
		Test Circuit 7 f = 10KHz	-75		dB	TYP
Total Harmonic Distortion	THD	f = 20Hz to 20KHz, V _{COM} = 3.5V _{P-P} , R _L = 600Ω, C _L = 50pF	0.065		%	TYP
Bandwidth -3 dB	BW	R _L = 50Ω, C _L = 5pF, Test Circuit 8	30		MHz	TYP
Source OFF Capacitance	C _{NC(OFF)} , C _{NO(OFF)}		82		pF	TYP
Channel ON Capacitance	C _{NC(ON)} , C _{NO(ON)} , C _{COM(ON)}		380		pF	TYP
POWER REQUIREMENTS						
Power Supply Current	I ₊	V ₊ = +5.5V, V _{IN} = 0V or 5V	0.001		μA	TYP
				1	μA	MAX

Specifications subject to change without notice.

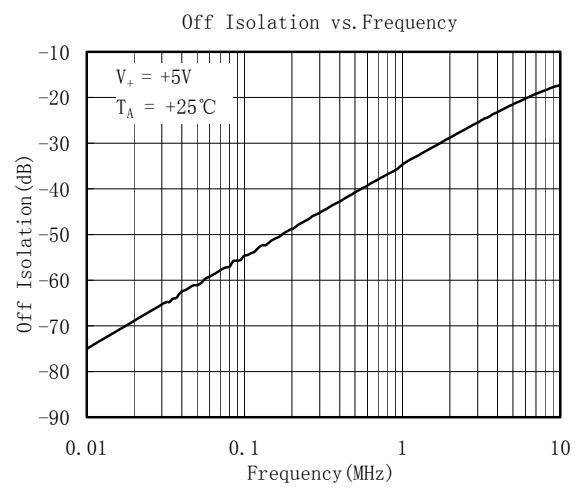
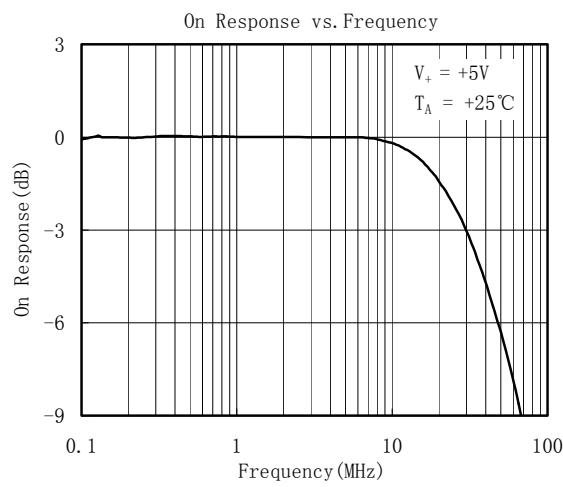
ELECTRICAL CHARACTERISTICS

(V₊ = +3 V ± 10%, GND = 0 V, T_A = - 40°C to +125°C, unless otherwise noted. Typical values are at T_A = + 25°C.)

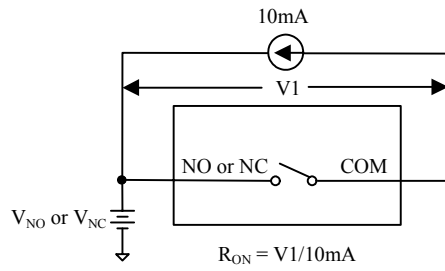
PARAMETER	SYMBOL	CONDITIONS	SGM3003			
			+25℃	- 40℃ to +125℃	UNITS	MIN/ MAX
ANALOG SWITCH						
Analog Signal Range	V _{NO} , V _{NC} , V _{COM}			0	V	MIN
				V ₊	V	MAX
On-Resistance	R _{ON}	0 ≤ V _{NO} or V _{NC} ≤ V ₊ , I _{COM} = -10 mA, Test Circuit 1	0.6		Ω	TYP
			1.0	1.3	Ω	MAX
On-Resistance Flatness	R _{FLAT(ON)}	0 ≤ V _{NO} or V _{NC} ≤ V ₊ , I _{COM} = -10 mA, Test Circuit 1	0.18		Ω	TYP
			0.3	0.4	Ω	MAX
LEAKAGE CURRENTS						
Source OFF Leakage current	I _{NC(OFF)} , I _{NO(OFF)}	V _{NO} or V _{NC} = 3V/1V, V _{COM} = 1V/3V, V ₊ = +3.3V ,Test Circuit 2	±5		nA	TYP
			±11	±1000	nA	MAX
Channel ON Leakage current	I _{NC(ON)} , I _{NO(ON)} , I _{COM(ON)}	V _{NO} or V _{NC} = V _{COM} = 1V or 3V, V ₊ = +3.3V , Test Circuit 3	±5		nA	TYP
			±11	±1000	nA	MAX
DIGITAL INPUTS						
Input High Voltage	V _{INH}			2.0	V	MIN
Input Low Voltage	V _{INL}			0.4	V	MAX
Input Current	I _{INL} or I _{INH}	V _{IN} = V _{INH} or V _{INL}	±0.01		μA	TYP
			±0.1	±1	μA	MAX
DYNAMIC CHARACTERISTICS						
Turn-On Time	t _{ON}	V _{NO} or V _{NC} = 2V, R _L = 300Ω, C _L = 35pF, Test Circuit 4	32		ns	TYP
Turn-Off Time	t _{OFF}	V _{NO} or V _{NC} = 2V, R _L = 300Ω, C _L = 35pF, Test Circuit 4	20		ns	TYP
Charge Injection,	Q	C _L = 1.0nF, V _G = 0V, R _G = 0, Test Circuit 5	10		pC	TYP
Break-Before-Make Time Delay	t _D	V _{NO1} or V _{NC1} = V _{NO2} or V _{NC2} = 2V, R _L = 300Ω, C _L = 35pF, Test Circuit 6	12		ns	TYP
Off Isolation	O _{ISO}	R _L = 50Ω, C _L = 5pF, f = 100KHz	-55		dB	TYP
		Test Circuit 7 f = 10KHz	-75		dB	TYP
Total Harmonic Distortion	THD	f = 20Hz to 20KHz, V _{COM} = 2V _{P-P} , R _L = 600Ω, C _L = 50pF	0.06		%	TYP
Bandwidth -3 dB	BW	R _L = 50Ω, C _L = 5pF, Test Circuit 8	30		MHz	TYP
Source OFF Capacitance	C _{NC(OFF)} , C _{NO(OFF)}		82		pF	TYP
Channel ON Capacitance	C _{NC(ON)} , C _{NO(ON)} , C _{COM(ON)}		380		pF	TYP
POWER REQUIREMENTS						
Power Supply Current	I ₊	V ₊ = +3.3V, V _{IN} = 0V or 3V	0.001		μA	TYP
				1	μA	MAX

Specifications subject to change without notice.

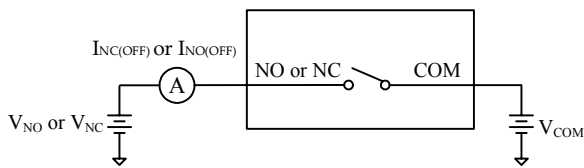
TYPICAL PERFORMANCE CHARACTERISTICS



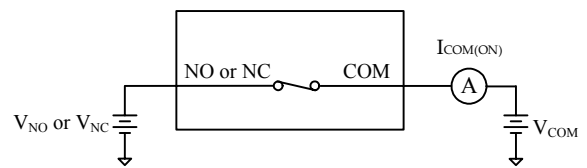
TEST CIRCUITS



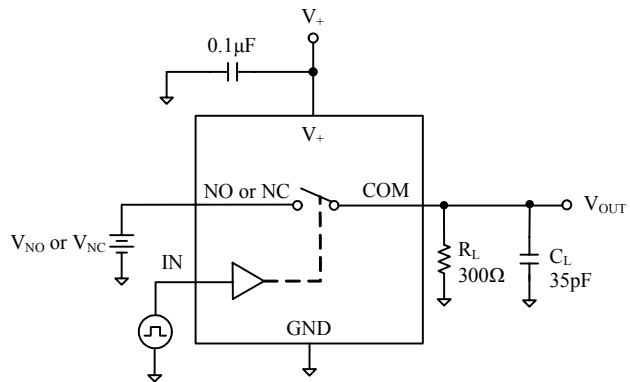
Test Circuit 1. On Resistance



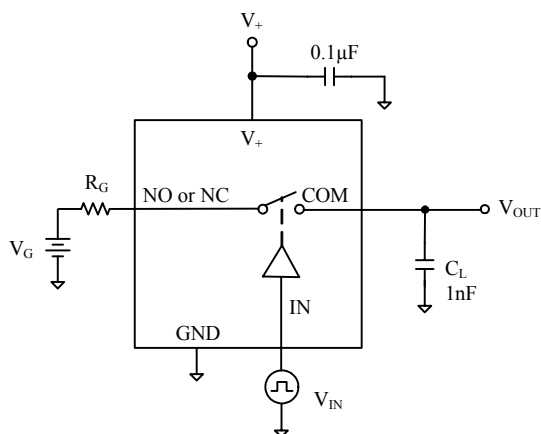
Test Circuit 2: Off Leakage



Test Circuit 3: On Leakage

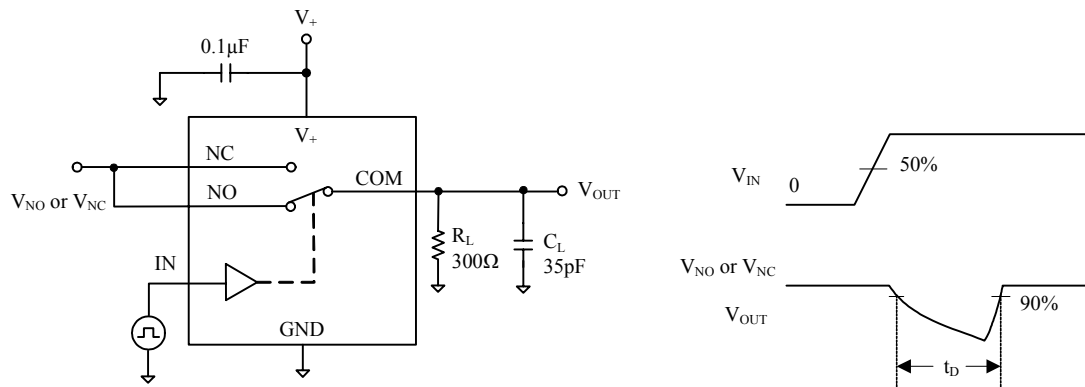


Test Circuit 4: Switching Times

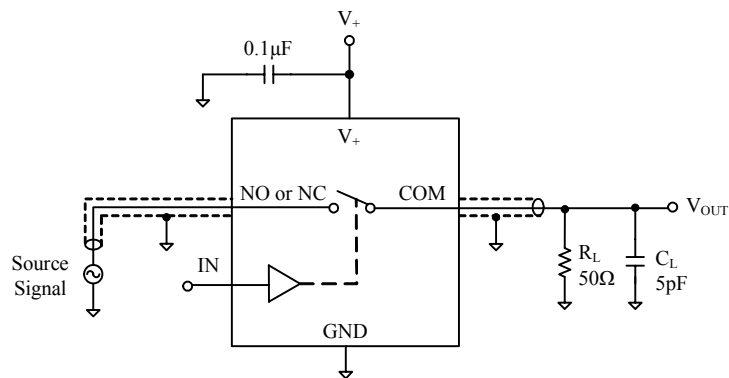


Test Circuit 5: Charge Injection

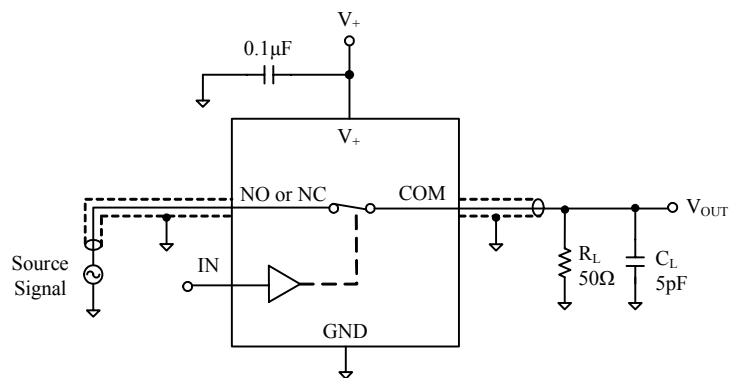
TEST CIRCUITS(Cont.)



Test Circuit 6. Break-Before-Make Time Delay, t_D



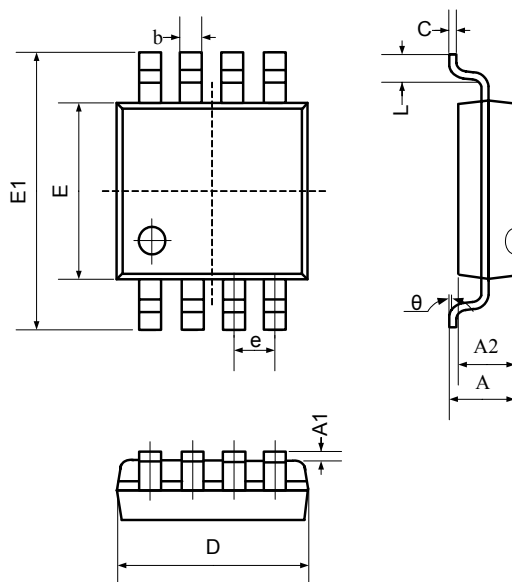
Test Circuit 7. Off Isolation



Test Circuit 8. Bandwidth

PACKAGE OUTLINE DIMENSIONS

MSOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.800	1.200	0.031	0.047
A1	0.000	0.200	0.000	0.008
A2	0.760	0.970	0.030	0.038
b	0.30 TYP		0.012 TYP	
c	0.15 TYP		0.006 TYP	
D	2.900	3.100	0.114	0.122
e	0.65 TYP		0.026 TYP	
E	2.900	3.100	0.114	0.122
E1	4.700	5.100	0.185	0.201
L	0.410	0.650	0.016	0.026
θ	0°	6°	0°	6°

REVISION HISTORY

Location	Page
11/06— Data Sheet changed from REV.A to REV.B	
Changes to ABSOLUTE MAXIMUM RATINGS	2
10/07— Data Sheet changed from REV.B to REV.C	
Changes to TYPICAL PERFORMANCE CHARACTERISTICS	5

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